

N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

Low On-Resistance

Low Gate Threshold Voltage

Low Input Capacitance

Fast Switching Speed

Low Input/Output Leakage

Ultra-Small Surface Mount Package

Lead Free/RoHS Compliant (Note 2)

Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

Case: SOT-523

Case Material: Molded Plastic. UL Flammability

Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020C

Terminals: Solderable per MIL-STD-202, Method 208

Lead Free Plating (Matte Tin Finish annealed over Alloy 42

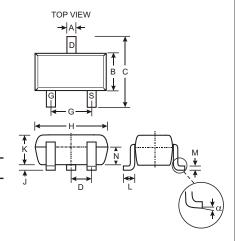
leadframe).

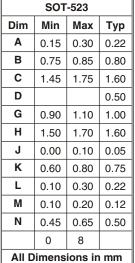
Terminal Connections: See Diagram

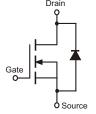
Marking: 72 (See Page 3)

Ordering & Date Code Information, See Page 3

Weight: 0.002 grams (approximate)







Maximum Ratings @ T_A = 25°C unless otherwise specified

Charac	teristic	Symbol	Value	Units		
Drain-Source Voltage		V _{DSS}	60	V		
Drain-Gate Voltage R _{GS} 1.0	DM	V_{DGR}	60	V		
Gate-Source Voltage	Continuous Pulsed	V _{GSS}	±20 ±40	V		
Drain Current (Note 1) Continuous Continuous @ 100°C Pulsed		I _D	115 73 800	mA		
Total Power Dissipation (Note	e 1)	P _d	150	mW		
Thermal Resistance, Junction	n to Ambient	R JA	833	°C/W		
Operating and Storage Temp	erature Range	T _j , T _{STG}	-55 to +150	°C		

Note: 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

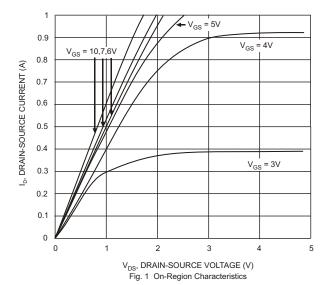
2. No purposefully added lead.

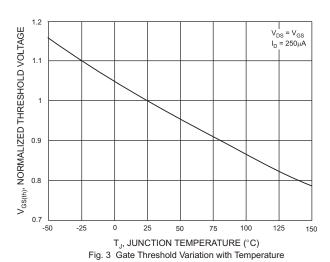


Electrical Chacteristics @ T_A = 25 C unless otherwise specified

Characteristic	Symbol Min		Тур	Тур Мах		Test Condition		
OFF CHARACTERISTICS (Note 3)								
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	V _{GS} = 0V, I _D = 10 A		
Zero Gate Voltage Drain Current @ $T_C = 25^{\circ}C$ @ $T_C = 125^{\circ}C$		I _{DSS}			1.0 500	μA	V _{DS} = 60V, V _{GS} = 0V	
Gate-Body Leakage		I _{GSS}			±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 3)								
Gate Threshold Voltage	V _{GS(th)}	1.0		2.0	V	$V_{DS} = V_{GS}, I_D = 250 A$		
Static Drain-Source On-Resistance	@ T _j = 25°C @ T _j = 125°C	В		2.0	7.5		$V_{GS} = 5.0V, I_D = 0.05A$	
	@ T _j = 125°C	R _{DS (ON)}		4.4	13.5		$V_{GS} = 10V, I_D = 0.5A$	
On-State Drain Current		I _{D(ON)}	0.5	1.0		Α	$V_{GS} = 10V, V_{DS} = 7.5V$	
Forward Transconductance		g _{FS}	80			mS	V _{DS} =10V, I _D = 0.2A	
DYNAMIC CHARACTERISTICS								
Input Capacitance	C _{iss}		22	50	pF			
Output Capacitance		Coss		11	25	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance		C _{rss}		2.0	5.0	pF	- 1.617112	
SWITCHING CHARACTERISTICS		'					,	
Turn-On Delay Time		t _{D(ON)}		7.0	20	ns	$V_{DD} = 30V, I_D = 0.2A,$	
Turn-Off Delay Time		t _{D(OFF)}		11	20	ns	$R_{L} = 150$, $V_{GEN} = 10V$, $R_{GEN} = 25$	

Note: 3. Short duration test pulse used to minimize self-heating effect.





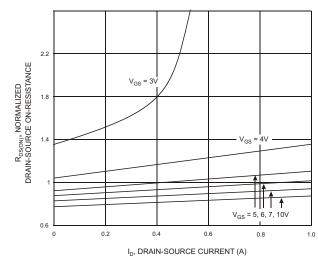


Fig. 2 On-Resistance Variation with Gate Voltage and Drain-Source Current

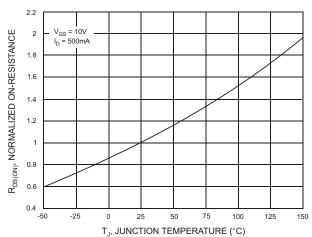
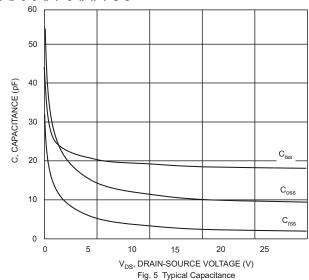
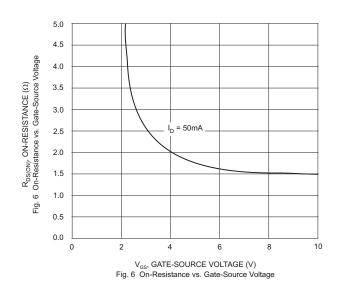


Fig. 4 On-Resistance Variation with Temperature





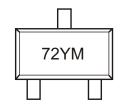


Ordering Information (Note 4)

Device	Packaging	Shipping			
2N7002T-7-F	SOT-523	3000/Tape & Reel			

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



72 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: N = 2002) M = Month (ex: 9 = September)

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009		
Code	N	Р	R	S	Т	U	V	W		

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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